

#### 20V N-Channel Enhancement Mode MOSFET

Voltage

20 V

Current

30 A

#### **Features**

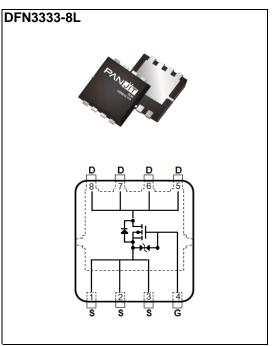
- $R_{DS(ON)}$ ,  $V_{GS}@4.5V$ ,  $I_{D}@10A<11m\Omega$
- $R_{DS(ON)}$ ,  $V_{GS}@2.5V$ ,  $I_{D}@9A<13m\Omega$
- R<sub>DS(ON)</sub>, V<sub>GS</sub>@1.8V, I<sub>D</sub>@8A<17mΩ</li>
- Advanced Trench Process Technology
- High density cell design for ultralow on-resistance
- Lead free in compliance with EU RoHS 2.0
- Green molding compound as per IEC 61249 standard

#### **Mechanical Data**

• Case: DFN3333-8L Package

• Terminals : Solderable per MIL-STD-750, Method 2026

• Approx. Weight: 0.03 grams



## **Maximum Ratings and Thermal Characteristics** (T<sub>A</sub>=25°C unless otherwise noted)

PARAMETER		SYMBOL	LIMIT	UNITS	
Drain-Source Voltage		V <sub>DS</sub>	20	V	
Gate-Source Voltage		$V_{GS}$	<u>+</u> 10		
Continuous Drain Current(Note 4)	Tc=25°C	I <sub>D</sub>	30		
	T <sub>C</sub> =100°C		19	Α	
Pulsed Drain Current(Note 1)	Tc=25°C	I <sub>DM</sub>	120		
Power Dissipation	T <sub>C</sub> =25°C	Po	26	10/	
	Tc=100°C		10.4	W	
Continuous Drain Current(Note 4)	T <sub>A</sub> =25°C	Ι <sub>D</sub>	11	^	
	T <sub>A</sub> =70°C		8	Α	
Power Dissipation	T <sub>A</sub> =25°C	Po	2	10/	
	T <sub>A</sub> =70°C		1.3	W	
Operating Junction and Storage Temperature Range		T <sub>J</sub> ,T <sub>STG</sub>	-55~150	°C	
Typical Thermal Resistance <sup>(Note 4,5)</sup>	Junction to Case	Rejc	4.8	°C/W	
	Junction to Ambient	$R_{\theta JA}$	62.5		

• Limited only By Maximum Junction Temperature



## **Electrical Characteristics** (T<sub>A</sub>=25°C unless otherwise noted)

PARAMETER	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNITS
Static						
Drain-Source Breakdown Voltage	BV <sub>DSS</sub>	BV <sub>DSS</sub> V <sub>GS</sub> =0V, I <sub>D</sub> =250uA	20	-	-	V
Gate Threshold Voltage	V <sub>GS(th)</sub>	V <sub>DS</sub> =V <sub>GS</sub> , I <sub>D</sub> =250uA	0.3	0.6	1	V
Drain-Source On-State Resistance	R <sub>DS(on)</sub>	V <sub>GS</sub> =4.5V, I <sub>D</sub> =10A	-	9.3	11	mΩ
		V <sub>GS</sub> =2.5V, I <sub>D</sub> =9A	-	11	13	
		V <sub>GS</sub> =1.8V, I <sub>D</sub> =8A	-	14.5	17	
Zero Gate Voltage Drain Current	I <sub>DSS</sub>	V <sub>DS</sub> =20V, V <sub>GS</sub> =0V	-	-	1	uA
Gate-Source Leakage Current	Igss	V <sub>GS</sub> = <u>+</u> 10V, V <sub>DS</sub> =0V	-	-	<u>+</u> 10	uA
Dynamic <sup>(Note 6)</sup>						
Total Gate Charge	$Q_g$	V <sub>DS</sub> =10V, I <sub>D</sub> =9A, V <sub>GS</sub> =4.5V <sup>(Note 2,3)</sup>	-	16	-	nC
Gate-Source Charge	Qgs		-	1.3	-	
Gate-Drain Charge	$Q_{gd}$		-	1.6	-	
Input Capacitance	Ciss	1/ 401/1/ 01/	-	1177	-	pF
Output Capacitance	Coss	V <sub>DS</sub> =10V, V <sub>GS</sub> =0V,	-	157	-	
Reverse Transfer Capacitance	Crss	f=1MHZ	-	134	-	
Turn-On Delay Time	td <sub>(on)</sub>	1/ 40\/ 1 44	-	16	-	ns
Turn-On Rise Time	tr	V <sub>DD</sub> =10V, I <sub>D</sub> =1A, V <sub>GS</sub> =4.5V, R <sub>G</sub> =25Ω <sup>(Note 2,3)</sup>	-	25	-	
Turn-Off Delay Time	td <sub>(off)</sub>		-	124	-	
Turn-Off Fall Time	t <sub>f</sub>	RG=25\(\int \text{(Note 2,3)}	-	101	-	
Drain-Source Diode						
Maximum Continuous Drain-Source					20	А
Diode Forward Current	ls		-	-	30	
Diode Forward Voltage	V <sub>SD</sub>	Is=1A, V <sub>GS</sub> =0V	-	0.73	1	V

#### NOTES:

- 1. Pulse width<300us, Duty cycle<2%.
- 2. Essentially independent of operating temperature typical characteristics.
- 3. Repetitive rating, pulse width limited by junction temperature T<sub>J(MAX)</sub>=150°C. Ratings are based on low frequency and duty cycles to keep initial T<sub>J</sub> =25°C.
- 4. The maximum current rating is package limited.
- 5. Rejah is the sum of the junction-to-case and case-to-ambient thermal resistance where the case thermal reference is defined as the solder mounting surface of the drain pins. Mounted on a 1 inch² with 2oz.square pad of copper.
- 6. Guaranteed by design, not subject to production testing.

February 18,2023 PJQ4416EP-REV.02 Page 2



#### **TYPICAL CHARACTERISTIC CURVES**

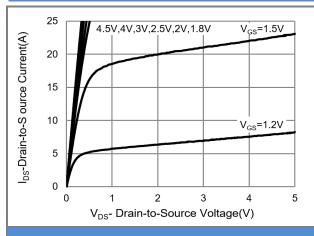
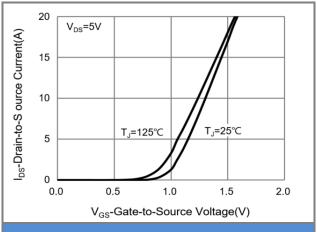


Fig.1 On-Region Characteristics



**Fig.2 Transfer Characteristics** 

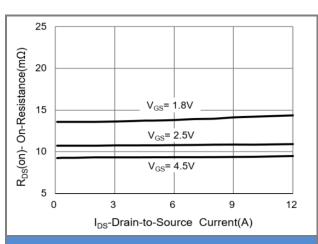


Fig.3 On-Resistance vs. Drain Current

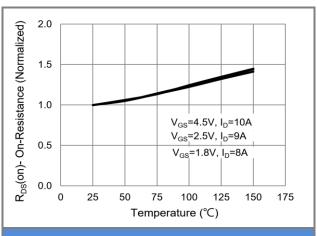


Fig.4 On-Resistance vs. Junction temperature

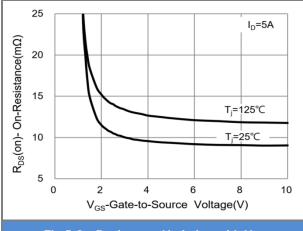


Fig.5 On-Resistance Variation with V<sub>GS</sub>

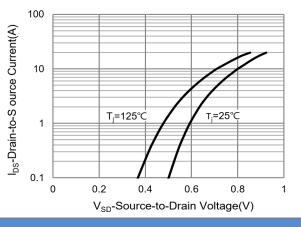


Fig.6 Source-Drain Diode Forward Voltage



#### **TYPICAL CHARACTERISTIC CURVES**

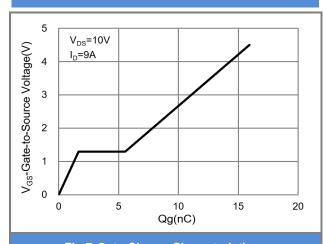


Fig.7 Gate-Charge Characteristics

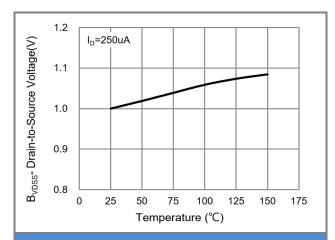


Fig.8 Breakdown Voltage Variation vs. Temperature

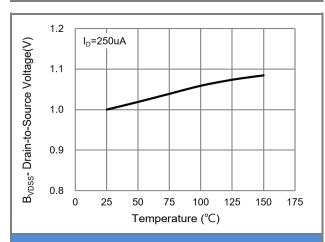


Fig.9 Threshold Voltage Variation with Temperature

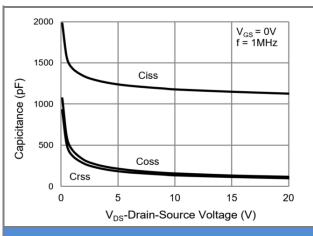


Fig.10 Capacitance vs. Drain-Source Voltage

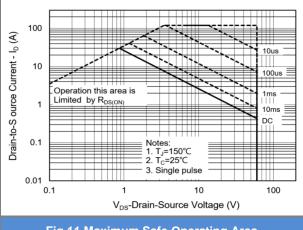


Fig.11 Maximum Safe Operating Area

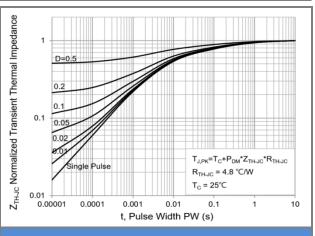


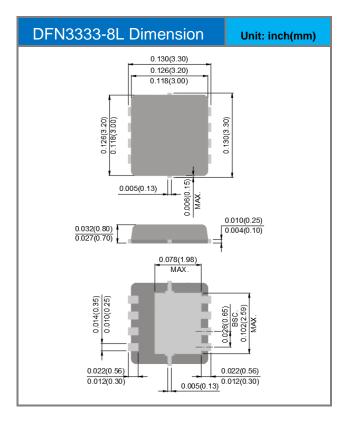
Fig.12 Normalized Transient Thermal Impedance

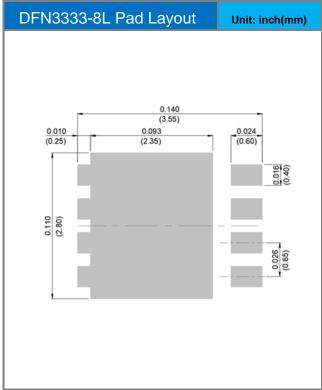


#### Part No. Packing Code Version

Part No. Packing Code	Package Type	Packing Type	Marking	Version
PJQ4416EP_R2_00001	DFN3333-8L	5K pcs / 13" reel	416E	Halogen free RoHS compliant

## **Packaging Information & Mounting Pad Layout**





February 18,2023 PJQ4416EP-REV.02 Page 5



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February 18,2023 PJQ4416EP-REV.02 Page 6

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